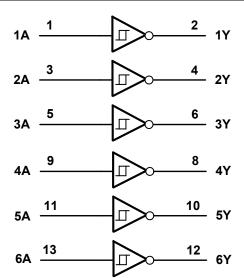


### **Pin Descriptions**

Pin Number	Pin Name	Function
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	Vcc	Supply Voltage

# **Logic Diagram**



### **Function Table**

Input	Output
Α	Υ
L	Н
Н	L

# **Absolute Maximum Ratings** (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < -0.5V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> < -0.5V	-20	mA
lok	Output Clamp Current V <sub>O</sub> > V <sub>CC</sub> +0.5V	25	mA
Io	Continuous Output Current -0.5V < V <sub>O</sub> V <sub>CC</sub> +0.5V	+/- 25	mA
I <sub>CC</sub>	Continuous Current Through V <sub>CC</sub>	75	mA
I <sub>GND</sub>	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

Note:

- Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values. V<sub>CC</sub> to the extent the maximum clamp current is exceeded.
   Unused inputs should be held at V<sub>CC</sub> or Ground.



## Recommended Operating Conditions (Note 5) @T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage		2.0	5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Free-Air Temperature		-40	+125	°C

Note: 5. Unused inputs should be held at  $V_{\text{CC}}$  or Ground.

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Cumbal	Parameter	Test Conditions	V	T <sub>A</sub> = -40°0	C to +85°C	T <sub>A</sub> = -40°C	to +125°C	Unit
Symbol	Parameter	rest Conditions	V <sub>CC</sub>	Min	Max	Min	Max	Oilit
	Positive-Going		3V		2.2		2.2	
$V_{T^+}$	Input Threshold		4.5V		3.15		3.15	V
	Voltage		5.5V		3.85		3.85	
	Negative-Going		3V	0.9		0.9		
$V_{T-}$	Input Threshold		4.5V	1.35		1.35		V
	Voltage		5.5V	1.65		1.65		
	Hystorogia		3V	0.3	1.2	0.25	1.2	
$\Delta V_{T}$	Hysteresis (V <sub>T+</sub> - V <sub>T-)</sub>		4.5V	0.4	1.4	0.35	1.4	V
(VI+ - VI-)		5.5V	0.5	1.6	0.45	1.6		
		I <sub>OH</sub> = -50μA	2.0V	1.9		1.9		V
		I <sub>OH</sub> = -50μA	3.0V	2.9		2.9		
$V_{OH}$	High Level Output Voltage	I <sub>OH</sub> = -50μA	4.5V	4.4		4.4		
	Voltage	I <sub>OH</sub> = -4mA	3.0V	2.48		2.40		
		I <sub>OH</sub> = -8mA	4.5V	3.80		3.70		
		I <sub>OL</sub> = 50μA	2.0V		0.1		0.1	
		I <sub>OL</sub> = 50μA	3.0V		0.1		0.1	1
$V_{OL}$	Low-level Output Voltage	I <sub>OL</sub> = 50μA	4.5V		0.1		0.1	V
	voltage	I <sub>OL</sub> = 4mA	3.0V		0.44		0.55	
		I <sub>OL</sub> = 8mA	4.5V		0.44		0.55	
lı	Input Current	V <sub>I</sub> = GND to 5.5V	3.6V		±1		±2	μA
I <sub>CC</sub>	Supply Current	$V_I = GND \text{ or } V_{CC_1} I_O = 0$	3.6V		20		40	μA

## **Operating Characteristics**

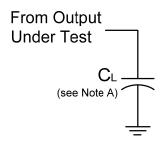
Parameter		Test Conditions	V <sub>CC</sub> = 2.0V Typ	V <sub>CC</sub> = 3.3V Typ	V <sub>CC</sub> = 5V Typ	Unit
$C_{\sf pd}$	Power Dissipation Capacitance per Gate	f = 1MHz	10.4	12.3	13	pF
Ci	Input Capacitance	$V_i = V_{CC} - \text{or GND}$	4.0	4.0	4.0	pF



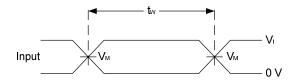
#### **Switching Characteristics**

Symbol	Parameter	Test	V	٦	Γ <sub>A</sub> = +25°C	;	-40°C to	o +85°C	-40°C to	+125°C	Unit
	Parameter	Conditions	V <sub>CC</sub>	Min	Тур	Max	Min	Max	Min	Max	Ullit
		Figure 1	3.0V to 3.6V	0.5	4.3	12.8	0.5	15.0	0.5	16.0	
	, Propagation	$C_L = 15pF$	4.5V to 5.5V	0.5	3.2	8.6	0.5	10.0	0.5	11.0	
t <sub>PD</sub>	Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1	3.0V to 3.6V	0.5	5.8	16.3	0.5	18.0	0.5	20.5	ns
		$C_L = 50pF$	4.5V to 5.5V	0.5	4.2	10.6	0.5	12.0	0.5	13.5	

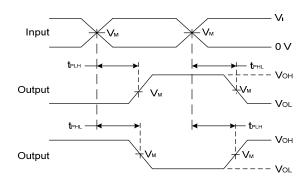
#### **Parameter Measurement Information**



V	Inp	outs	V	_
Vcc	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	C <sub>L</sub>
3.3V -3.6V	Vcc	3ns	V <sub>CC</sub> /2	15pF, 50pF
4.5V to 5.5V	V <sub>CC</sub>	3ns	V <sub>CC</sub> /2	15pF, 50pF



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

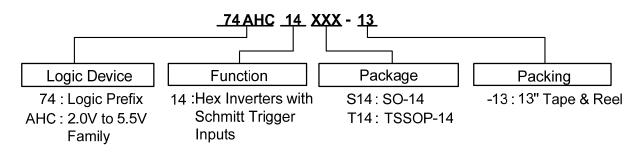
Figure 1 Load Circuit and Voltage Waveforms

Notes: A . Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$ .



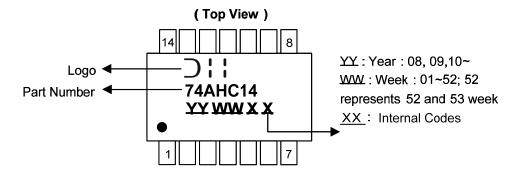
#### **Ordering Information**



	Device	Package Code	Packaging	7" Tape a	and Reel
	Device	Package Code	Packaging	Quantity	Part Number Suffix
Pby Lead free Green	74AHC14S14-13	S14	SO-14	2500/Tape & Reel	-13
Pby Lead free Green	74AHC14T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

### **Marking Information**

(1) SO-14, TSSOP-14



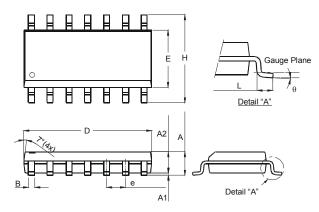
Part Number	Package
74AHC14S14	SO-14
74AHC14T14	TSSOP-14



# Package Outline Dimensions (All dimensions in mm.)

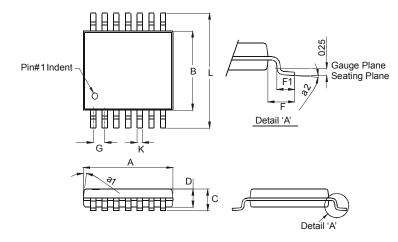
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

#### Package Type: SO-14



	SO-14				
Dim	Min	Max			
Α	1.47	1.73			
A1	0.10	0.25			
A2	1.45	Тур			
В	0.33	0.51			
D	8.53	8.74			
Е	3.80	3.99			
е	1.27	Тур			
Н	5.80	6.20			
٦	0.38	1.27			
θ	0°	8°			
All Di	All Dimensions in mm				

#### Package Type: TSSOP-14



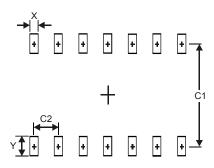
-	TSSOP-14					
Dim	Min	Max				
a1	7° (	4X)				
a2	0°	8°				
Α	4.9	5.10				
В	4.30	4.50				
O		1.2				
D	8.0	1.05				
F	1.00	Тур				
F1	0.45	0.75				
G	0.65	Тур				
K	0.19	0.30				
Ĺ	6.40 Typ					
All Din						



## **Suggested Pad Layout**

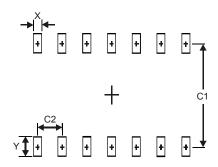
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

#### Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

#### Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65



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